

AMENDMENTS TO THE CLAIMS

Please amend Claim 1.

1. (Currently amended) An optical interference display unit at least comprising:
a first electrode;
a second electrode, in parallel with the first electrode and comprising:
a material layer; and
a conductive layer on the material layer; and
a support structure partially covered by the second electrode and supporting an edge of the second electrode;
wherein a material of the conductive layer is more difficult to be etched than a material of the material layer.
2. (Original) The optical interference display unit of Claim 1, wherein the optical interference display unit is located on a substrate.
3. (Original) The optical interference display unit of Claim 2, wherein the substrate is a transparent substrate.
4. (Original) The optical interference display unit of Claim 1, wherein a material of the first electrode is a conductive transparent material.
5. (Original) The optical interference display unit of Claim 4, wherein the conductive transparent material is indium tin oxide (ITO), indium zinc oxide (IZO), or indium oxide (IO).
6. (Original) The optical interference display unit of Claim 1, wherein the second electrode is a deformable electrode.
7. (Original) The optical interference display unit of Claim 1, wherein the second electrode is a movable electrode.
8. (Original) The optical interference display unit of Claim 1, wherein a material for forming the support structure is selected from a group consisting of positive photoresist, negative photoresist, acrylic resin and epoxy resin.
9. (Previously presented) The optical interference display unit of Claim 1, wherein the material layer is made from a conductive material.

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10. (Previously presented) The optical interference display unit of Claim 1 , wherein the material layer is made from dielectric material.

11. (Previously presented) The optical interference display unit of Claim 9 , wherein a material for forming the material layer is aluminum, chromium, cobalt, copper, silicon nitride or silicon oxide.

12. (Previously presented) The optical interference display unit of Claim 1 , wherein a material for forming the conductive layer is aluminum, chromium, cobalt, copper, silicon nitride or silicon oxide.

13. (Canceled)